

Kxxx1GL Series

RoHS



Schematic Symbol



Applications

Typical application circuit presented in Figure 10 of this data sheet (Typical Metal Halide Ignitor Circuit).

Description

The Multipulse™ SIDAC is a voltage switch used in Metal-Halide lamp ignition circuits, as well as High Pressure Sodium lamp ignition circuits for outdoor street and area lighting. This robust solid-state switch is designed to handle lamp igniter applications requiring operation at ambient temperatures up to 90°C where igniter circuit components can raise SIDAC junction temperature up to 125°C, especially when the lamp element is removed or ruptured. Its excellent commutation time (t_{COMM}) makes this robust product best suited for producing multiple pulses in each half cycle of 50/60 Hz line voltage. The Multipulse™ SIDAC is offered in a DO-15 axial leaded package.

Kxxx1GL SIDAC has a repetitive off-state blocking voltage (V_{DRM}) of 180V to 270V minimum depending actual device type. Blocking capability is ensured by glass passivated junctions for best reliability. The package is epoxy encapsulated with tin plated copper alloy leads.

Features

- AC circuit oriented
- RoHS Compliant
- Triggering Voltage of 200 to 380V

Electrical Specifications

Symbol	Parameters	Test Conditions	Min	Max	Unit
V_T	On-state Voltage	$I_T=1A$		3	V
I_{TRM}	Peak Non-Repetitive Surge Current	$T_A=25^\circ C$ Pulse Wave = 10 μs , Sine Wave, $f=120Hz$		50	A
V_{BO}	Breakover/Trigger Voltage	K2201GL K2401GL K2501GL K3601GL	200 220 240 348	230 250 265 380	V
V_{DRM}	Repetitive Peak Off-State Voltage	K2201GL K2401GL K2501GL K3601GL	180 190 200 270		V
$I_{T(RMS)}$	On-State RMS Current, $T_J < 125^\circ C$	50/60Hz Sine Wave		1	A
I_H	Dynamic Holding Current, $R=100\ \Omega$	50/60Hz Sine Wave		30 TYP	mA
R_S	Switching Resistance, $R_S = \frac{(V_{BO} - V_S)}{(I_S - I_{BO})}$	50/60Hz Sine Wave	100		Ω
t_{COMM}	Commutation Time $T_J < 125^\circ C$	See test circuit and waveform in Figure 9		100	μsec
I_{BO}	Breakover Current	50/60Hz Sine Wave		10	μA
I_{TSM}	Non-repetitive 1 cycle On-State peak value	60Hz 50Hz		20.0 16.7	A
di/dt	Critical Rate of Rise of On-State Current			150	A/ μsec
dv/dt	Critical Rate of Rise of Off-State Voltage			1500	V/ μsec
T_S	Storage Temperature Range		-40	+125	$^\circ C$

Figure 1: Characteristics

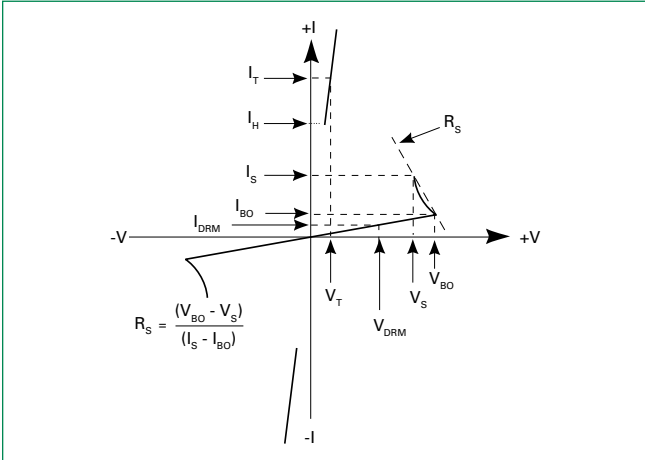


Figure 2: Maximum Allowable Lead/Tab Temperature vs. On-State Current



Figure 3: Power Dissipation (Typical) vs. On-State Current

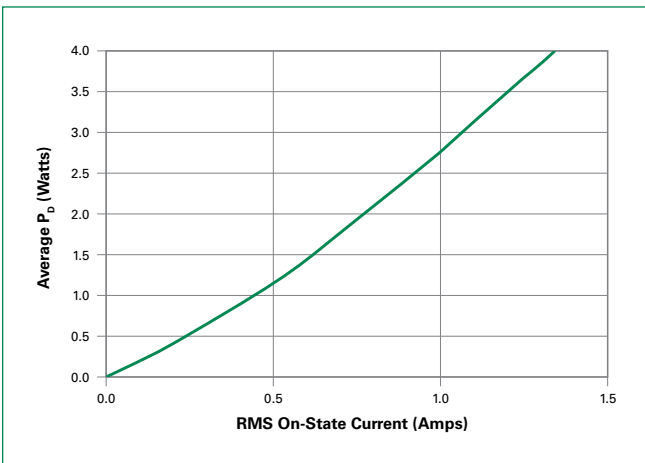


Figure 4: V_{BO} Change vs. Junction Temperature



Figure 5: Pulse On-State Current Rating

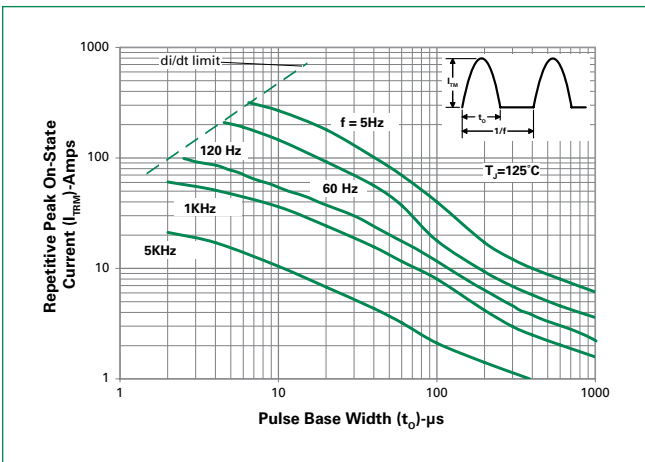


Figure 6: Maximum Allowable Ambient Temperature vs. On-State Current



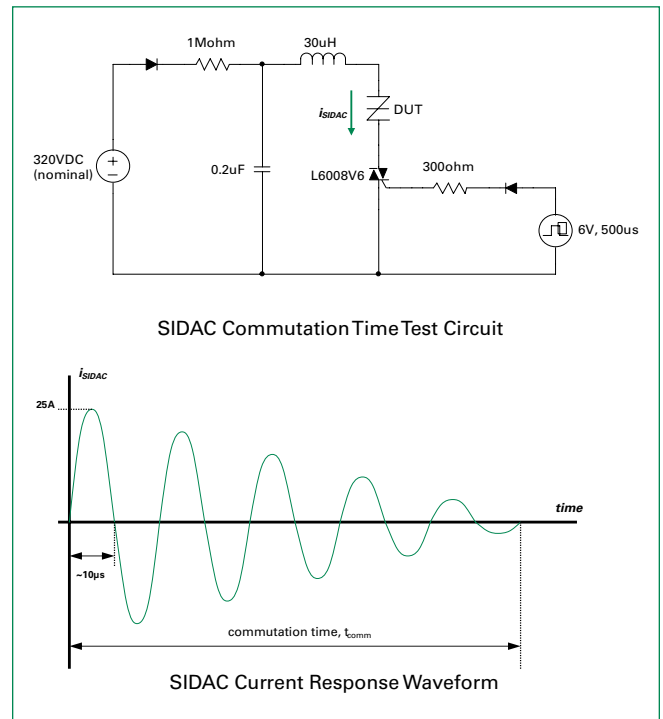
Figure 7: Peak Surge Current vs Surge Current Duration



Figure 8: Typical On-State Voltage vs On-State Current



Figure 9: Multipulse™ SIDAC t_{COMM} Commutation Time



Additional Information



Datasheet



Resources



Samples

Figure 10: Typical Metal Halide Ignitor Circuit



Note: With proper component selection, this circuit will produce three pulses for ignition of metal halide lamp that requires a minimum of three pulses at 5kV magnitude and >1uSec duration each at a minimum repetition rate of 3.3kHz.

Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	- Temperature Min ($T_{s(min)}$)	150°C
	- Temperature Max ($T_{s(max)}$)	200°C
	- Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus Temp) (T_L) to peak		5°C/second max
$T_{s(max)}$ to T_L - Ramp-up Rate		5°C/second max
Reflow	- Temperature (T_L) (Liquidus)	217°C
	- Temperature (t_L)	60 – 150 seconds
Peak Temperature (T_p)		260 ^{+0/-5} °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		5°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes Max.
Do not exceed		280°C



Physical Specifications

Terminal Finish	100% Matte Tin Plated
Body Material	UL recognized epoxy meeting flammability classification 94V-0
Lead Material	Copper Alloy

Package	Weight / unit (mg)
DO-15	385

Design Considerations

Careful selection of the correct device for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Overheating and surge currents are the main killers of SIDACs. Correct mounting, soldering, and forming of the leads also help protect against component damage.

Reliability/Environmental Tests

Test	Specifications and Conditions
High Temperature Voltage Blocking	MIL-STD-750: Method 1040, Condition A Rated V_{DRM} (VAC-peak), 125°C, 1008 hours
Temperature Cycling	MIL-STD-750: Method 1051, 100 cycles; -40°C to 150°C, 15-minute dwell time
Temperature / Humidity	EIA/JEDEC: JESD22-A101 1008 hours; 160V - DC: 85°C; 85% relative humidity
High Temp Storage	MIL-STD-750: Method 1031 150°C, 1008 hours
Low-Temp Storage	-40°C, 1008 hours
Thermal Shock	MIL-STD-750: Method 1056 10 cycles; 0°C to 100°C; 5-minute dwell-time at each temperature; 10-sec (max) transfer time between temperature
Autoclave	EIA/JEDEC: JESD22-A102 168 hours (121°C at 2 ATMs) and 100% RH
Resistance to Solder Heat	MIL-STD-750: Method 2031 260°C, 10 seconds
Solderability	ANSI/J-STD-002: Category 3, Test A
Repetitive Surge Life Testing	Multi firings per half cycle at 60Hz in application circuit for 168 hours minimum

Dimensions — DO-15 (G Package)



Dimension	Inches		Millimeters	
	Max	Max	Min	Max
B	0.028	0.034	0.711	0.864
D	0.120	0.140	3.048	3.556
G	0.235	0.270	5.969	6.858
L	1.000		25.400	

Product Selector

Part Number	Switching Voltage Range		Blocking Voltage	Packages
	V_{BO} Minimum	V_{BO} Maximum	V_{DRM}	
K2201GL	200V	230V	180V	DO-15
K2401GL	220V	250V	190V	DO-15
K2501GL	240V	265V	200V	DO-15
K3601GL	340V	380V	270V	DO-15

Packing Options

Part Number	Package	Packing Mode	Base Quantity
Kxxx1GL	DO-15	Bulk	1000
Kxxx1GLRP		Tape & Reel	5000

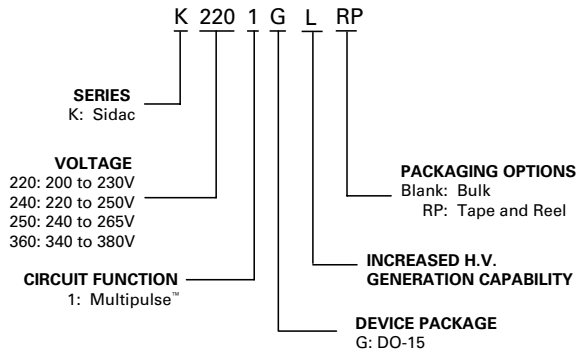
Note: xxx = voltage

DO-15 Embossed Carrier RP Specifications

Meets all EIA RS-29-6 Standards



Part Numbering System



Part Marking System



Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9